



A Product Line of **Diodes Incorporated**



100V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

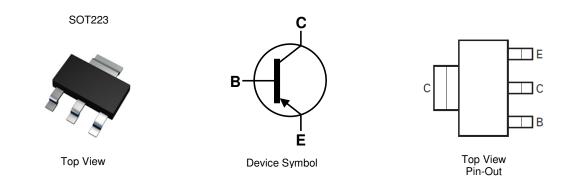
- $BV_{CEO} > -100V$
- I_C = -5A High Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -90mV @ -1A
- $R_{SAT} = 60m\Omega$ for a Low equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

- Motor Driving
- Line Switching
- **High Side Switches**
- Subscriber Line Interface Cards (SLIC)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
ZX5T953GTA	AEC-Q101	X5T953	7	12	1,000	
ZX5T953GQTA	Automotive	X5T953	7	12	1,000	
Notes: 1, EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.						

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http:// www.diodes.com/products/packages.html.

Marking Information

	SOT223	
F		-
	X5T 953	YWW
		Η

X5T953 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)





ZX5T953G

Maximum Ratings (@ $T_A = +25 \,^{\circ}$ C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	lc	-5	А
Peak Pulse Current	I _{CM}	-10	A

Thermal Characteristics (@T_A = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)		3.0 24	W	
Linear Derating Factor	(Note 7)	PD	1.6 12.8	mW /℃	
Thermal Registeres, Junction to Ambient	(Note 6)	$R_{ extsf{ heta}JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 7)	R _{θJA}	78	°C/W	
Thermal Resistance Junction to Lead	(Note 8)	$R_{ extsf{ heta}JL}$	10.4		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

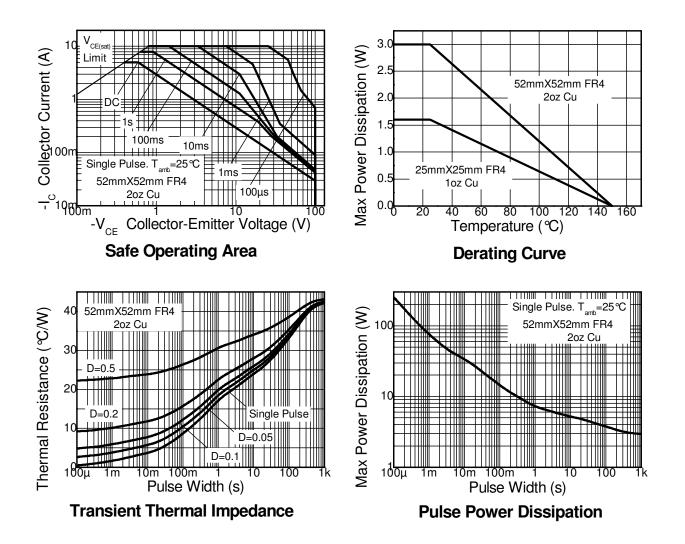
Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.







Thermal Characteristics and Derating Information







ZX5T953G

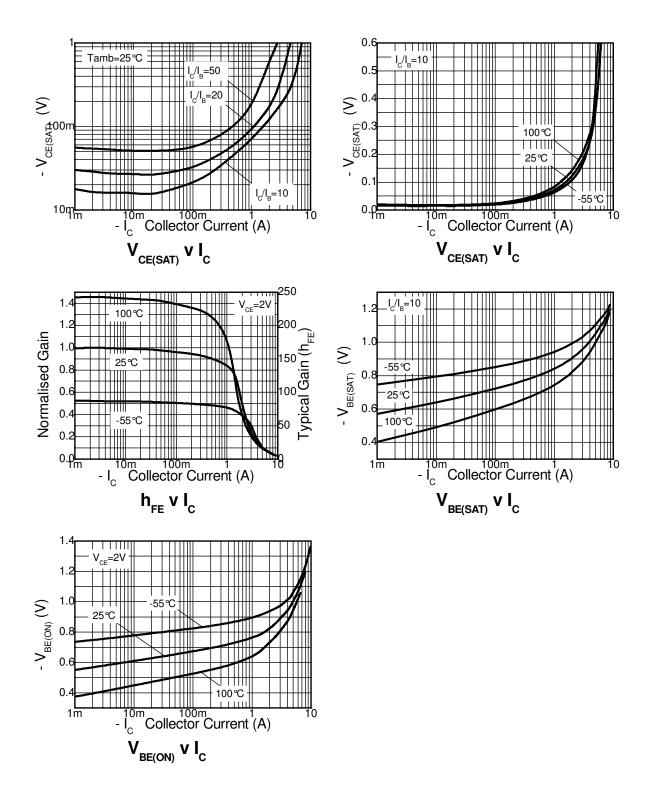
Electrical Characteristics (@T _A = +25 °C, unless otherwise specified.)						
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-140	-160	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	-140	-160	-	V	I _C = -1μA, RB ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-115	-	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	-	V	I _E = -100μA
Collector-Base Cut-Off Current	I _{CBO}	-	<1 -	-20 -0.5	nA μA	V _{CB} = -100V V _{CB} = -100V, T _A = +100 °C
Collector-Emitter Cut-Off Current	I _{CER} R ≤ 1kΩ	-	<1 -	-20 -0.5	nA μA	V _{CB} = -100V V _{CB} = -100V, T _A = +100 °C
Emitter Cut-Off Current	I _{EBO}	-	<1	-10	nA	$V_{EB} = -6V$
	h _{FE}	100	250	-		I _C = -10mA, V _{CE} = -1V
		100	200	300	-	$I_{C} = -1A, V_{CE} = -1V$
Static Forward Current Transfer Ratio (Note 10)		25	50	-		$I_{C} = -3A, V_{CE} = -1V$
		15	30	-		$I_{C} = -4A, V_{CE} = -1V$
		-	5	-		$I_{C} = -10A, V_{CE} = -1V$
	V _{CE(sat)}	-	-20	-30	mV	$I_{C} = -100 \text{mA}, I_{B} = -10 \text{mA}$
Collector-Emitter Saturation Voltage (Note 10)		-	-70	-90		$I_{C} = -1A, I_{B} = -100mA$
		-	-120	-150		$I_{C} = -2A, I_{B} = -200mA$
		-	-240	-340		$I_{C} = -4A, I_{B} = -400mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-985	-1100	mV	$I_C = -4A, I_B = -400mV$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	-	-920	-1050	mV	$I_{C} = -4A, V_{CE} = -2V$
Output Capacitance (Note 10)	Cobo	-	42	-	pF	V _{CB} = -10V. f = 1MHz
Transition Frequency	fT	-	125	-	MHz	$V_{CE} = -10V$, $I_C = -100mA$ f = 50MHz
Switching Time	t _{on}	-	42	-	ns	$V_{CC} = -10V, I_{C} = -1A$
	t _{off}	-	540	-	115	$I_{B1} = I_{B2} = -100 \text{mA}$

10. Measured under pulsed conditions. Pulse width \leq 300 $\mu s.$ Duty cycle \leq 2%. Note:





Typical Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)



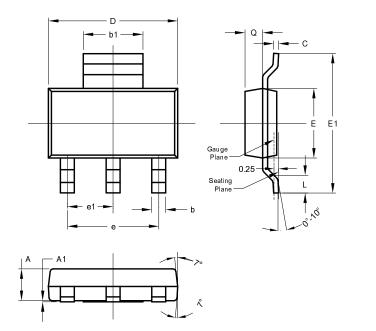




ZX5T953G

Package Outline Dimensions

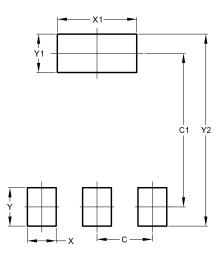
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between Note: device terminals and PCB tracking.





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